

Data Sheet Rev 01.1220

100GBASE-SR4 850nm MMF 100m QSFP28 Optical Transceiver with Duplex MPO Connector

100GSRSFPCM



DESCRIPTION

The 100GSRSFPCM QSFP28 100GBASE-SR4 optical transceiver is a new high-speed module with a MPO connector. This interconnecting module offers 4 channels and maximum bandwidth of 100Gbps. The TRxs utilize multimode fiber with 850-nm VCSELs and PIN PDs. This module provides high performance and excellent efficiency in the optical communication.

FEATURES

- Compliant with 100G Ethernet IEEE 802.3bm 100GBASE-SR4 standards
- Compliant to SFF-8636 QSFP28 MSA
- QSFP footprint (Quad small form-factor, pluggable)
- Power consumption <3.5W
- Full Digital Diagnostics Monitor Interface
- Case Temperature Operating Range: 0°C to 70°C
- Hot pluggable electrical interface
- RoHS-6 Compliant
- Up to 70m over OM3 fiber
- Up to 100m over OM4 fiber

APPLICATION

- 100GBASE-SR4 Ethernet links
- Infiniband EDR, FDR & QDR interconnects

ABSOLUTE MAXIMUM RATINGS

PARAMETER	SYMBOL	MIN	MAX	UNIT
Storage Temperature	Ts	-40	85	°C
3.3V Power Supply Voltage	Vcc	-0.5	3.6	V
Data Input Voltage – Single Ended		-0.5	Vcc+0.5	V
Relative Humidity	RH	5	85	%

Note: Exceeding these values may cause permanent damage. Function operation under these conditions is not implied.

RECOMMENDED OPERATING CONDITIONS

PARAMETER	SYMBOL	MIN	TYP.	MAX	UNIT
Case Operating Temperature	Tc	0		70	°C
3.3V Power Supply Voltage	Vcc	3.14	3.3	3.46	V
Signal Rate per Channel	В		25.78125		Gb/s
Control Input Voltage High	Vih	2		Vcc+0.3	V
Control Input Voltage Low	Vil	-0.3		0.8	V
Two Wire Serial (TWS) Interface Clock Rate				400	KHz
Receiver Differential Data Output Load	Zd		100		Ohms
Power Supply Current	Icc			1060	mA
Power Consumption	Р	-		3.5	W

TRANSMITTER ELECTRO-OPTICAL CHARACTERISTICS

PARAMETER	SYMBOL	MIN	TYP.	MAX	UNIT	NOTES
Center Wavelength	λc	840		860	nm	
Spectral Width (RMS)	Δλ			0.6	nm	
Average Output Power, each lane	Pout	-8.4		+2.4	dBm	
Optical Modulation Amplitude (OMA)	POMA	-6.4		+3	dBm	
Launch power in OMA minus TDEC, each lane		-7.3			dBm	
Transmitter and dispersion eye closure (TDEC), each	TDEC			4.3	dB	
lane						
Optical Extinction Ratio	ER	2			dB	
Disabled Output Optical Power	PO_OFF			-30	dBm	
Eye Mask Coordinates: X1, X2, X3; Y1, Y2, Y3		0.3, 0.38, 0.45, 0.35, 0.41, 0.5		UI	(1)	
Optical Return Loss Tolerance				12	dB	
Differential Data Input Voltage	VDIFF	300		900	mV	

RECEIVER ELECTRO-OPTICAL CHARACTERISTICS

PARAMETER	SYMBOL	MIN	TYP.	MAX	UNIT	NOTES
Center Wavelength, each lane	λ	840	850	860	nm	
Damage Threshold	DTH	3.4			dBm	
Average Receiver Power, each lane	PIN_AVG	-10.3		+2.4	dBm	(2)
Stressed Sensitivity (OMA)	PIN_s-oma			-5.2	dBm	(3)
LOS Assert	PA	-30			dBm	
LOS De-Assert	PD			-11	dBm	
LOS Hysteresis		0.5			dBm	
Rise & Fall Time (20%~80%)	Tr/Tf			35	ps	
Differential Data Output Voltage	V _{out,pp}	300		900	mV	

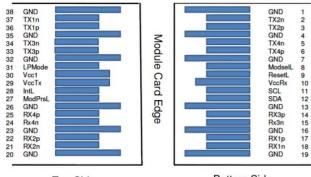
Notes:

1. Hit ratio = 5×10^{-5} per sample

2. Average receive power, each lane (min) is informative and not the principal indicator of signal strength.

3. Measured with conformance test signal for BER=5x10⁻⁵

PAD ASSIGNMENT AND DESCRIPTION



Top Side Viewed From Top

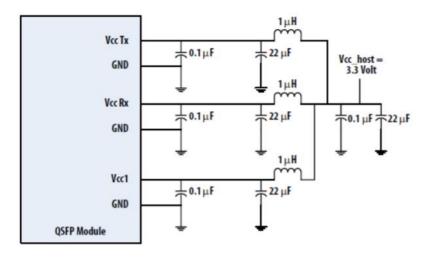
Bottom Side Viewed From Bottom

PIN	LOGIC	SYMBOL	DESCRIPTION	PLUG SEQUENCE	NOTE
1		GND	Ground	1	Note 1
2	CML-I	Tx2n	Transmitter Inverted Data Input	3	
3	CML-I	Tx2p	Transmitter Non-Inverted Data Input	3	
4		GND	Ground	1	Note 1
5	CML-I	Tx4n	Transmitter Inverted Data Input	3	
6	CML-I	Tx4p	Transmitter Non-Inverted Data Input	3	
7		GND	Ground	1	Note 1
8	LVTTL-I	ModSelL	Module Select	3	
9	LVTTL-I	ResetL	Module Reset	3	
10		Vcc Rx	+3.3V Power Supply Receiver	2	Note 2
11	LVCMOS-I/O	SCL	2-wire serial interface clock	3	
12	LVCMOS-I/O	SDA	2-wire serial interface data	3	
13		GND	Ground	1	Note 2
14	CML-O	Rx3p	Receiver Non- Inverted Data Output	3	
15	CML-O	Rx3n	Receiver Inverted Data Output	3	
16		GND	Ground	1	Note 1
17	CML-O	Rx1p	Receiver Non- Inverted Data Output	3	
18	CML-O	Rx1n	Receiver Inverted Data Output	3	
19		GND	Ground	1	Note 1
20		GND	Ground	1	Note 1
21	CML-O	Rx2n	Receiver Inverted Data Output	3	
22	CML-O	Rx2P	Receiver Non- Inverted Data Output	3	
23		GND	Ground	1	Note 1
24	CML-O	Rx4n	Receiver Inverted Data Output	3	
25	CML-O	Rx4p	Receiver Non- Inverted Data Output	3	
26		GND	Ground	1	Note 1
27	LVTTL-O	ModPrsL	Module Present	3	
28	LVTTL-O	IntL	Interrupt	3	
29	LVCMOS-I/O	Vcc Tx	+3.3V Power Supply transmitter	2	Note 2
30		Vcc1	+3.3V Power Supply	2	Note 2
31	LVTTL-I	LPMode	Low Power Mode	3	
32		GND	Ground	1	Note 1
33	CML-I	Tx3p	Transmitter Non- Inverted Data Input	3	
34	CML-I	Tx3n	Transmitter Inverted Data Input	3	
35		GND	Ground	1	Note 1
36	CML-I	Tx1p	Transmitter Non- Inverted Data Input	3	
37	CML-I	Tx1n	Transmitter Inverted Data Input	3	
38		GND	Ground	1	Note 1

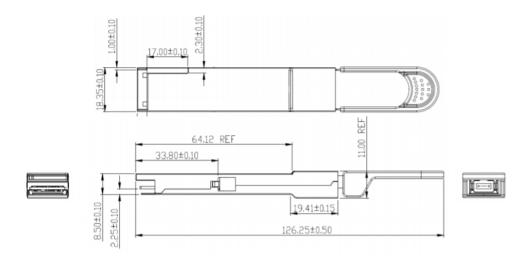
Note 1: GND is the symbol for signal and supply (power) common for the QSFP module. All are common within the QSFP+ module and all module voltages are referenced to this potential unless otherwise noted. Connect these directly to the host board signal-common ground plane.

Note 2: Vcc Rx, Vcc1 and Vcc Tx are the receiver and transmitter power supplies and shall be applied concurrently. Requirements defined for the host side of the Host Edge Card Connector are listed in Table. Recommended host board power supply filtering is shown in Host board power supply circuit. Vcc Rx Vcc1 and Vcc Tx may be internally connected within the QSFP+ module in any combination. The connector pins are each rated for a maximum current of 500 mA.

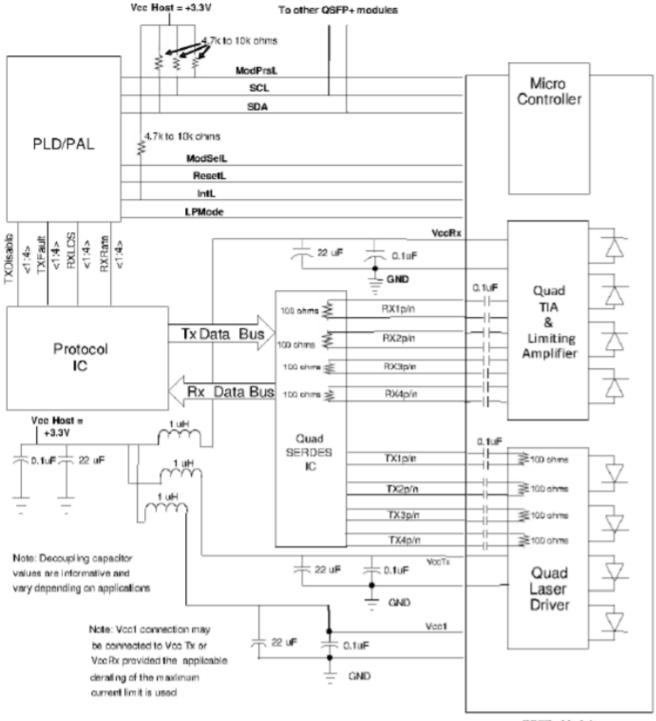
HOST BOARD POWER SUPPLY CIRCUIT



DIMENSIONS (unit: mm)

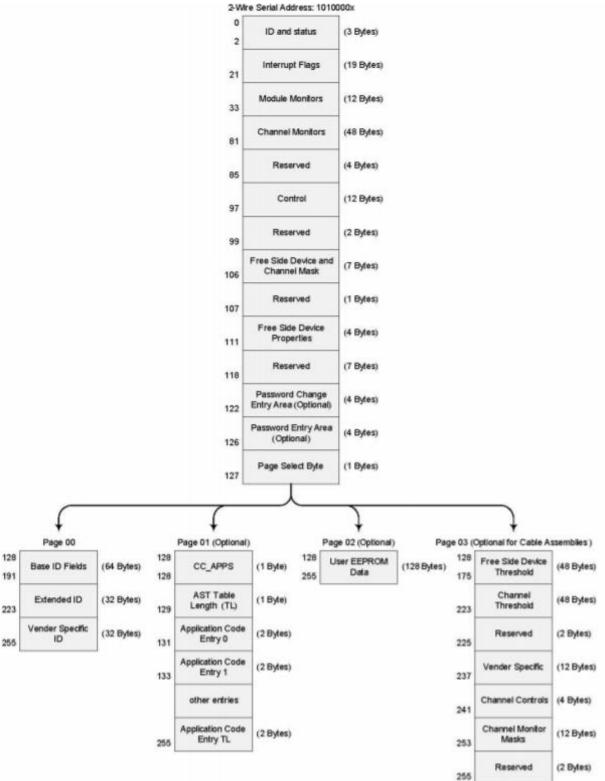


RECOMMENDED INTERFACE CIRCUIT



QSFP+ Module

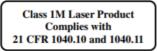
MEMORY MAP



EYE SAFETY MARK

The multimode transceiver is a class 1M laser product. It complies with EN 60825-1:2007 and FDA 21 CFR 1040.10 and 1040.11. In order to meet laser safety requirements, the transceiver shall be operated within the Absolute Maximum Ratings.

Required Mark



[CAUTION] All adjustments have been done at the factory before the shipment of the devices. No maintenance and user serviceable part are required. Tampering with and modifying the performance of the device will result in voided product warranty.

Use of controls or adjustment or performance of procedures other than those specified herein may result in hazardous radiation exposure.

Complies with FDA performance standards for laser products except for deviations pursuant to Laser Notice No. 50.

ADDITIONAL NOTES

- Avoid eye or skin exposure to laser radiations.
- The device is sensitive to electro-static discharge (ESD). The device should be handled with ESD proof tools. To assemble the device on PCB, proper grounding is required to prevent ESD.
- Specifications are subject to change without notice.



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